

FPF2495 IntelliMAX[™] 28 V, Over-Voltage, Over-Current Protection Load Switch with Adjustable Current-Limit Control

Features

- V_{IN}: 2.5 V~5.5 V
- 28 V Absolute Ratings at V_{OUT}
- Current Capability: 2 A
- Adjustable Current Limit: 0.05 A ~ 2 A (Typ.)
 - 0.1 A~2 A with 10% Accuracy
 - < 0.1A with 15% Accuracy</p>
- R_{on}: Maximum 100 m Ω at 5 V_{IN} and 1 A I_{OUT}
- Output OVP: Min.=5.6 V, Typ.=5.8 V, Max.=6 V
- No Output Discharge During Off State
- Open-Drain OCP on FLAGB
- Thermal Shutdown
- Under-Voltage Lockout (UVLO)
- True Reverse-Current Blocking (TRCB)
- Logic CMOS IO Meets JESD76 Standard for GPIO Interface and Related Power Supply Requirements
- ESD Protected:
 - Human Body Model: >2 kV
 - Charged Device Model: >2.5 kV
 - IEC 61000-4-2 Air Discharge: >15 kV
 - IEC 61000-4-2 Contact Discharge: >8 kV

Applications

Smart Phones, Tablet PCs

Ordering Information

Storage, DSLR, and Portable Devices

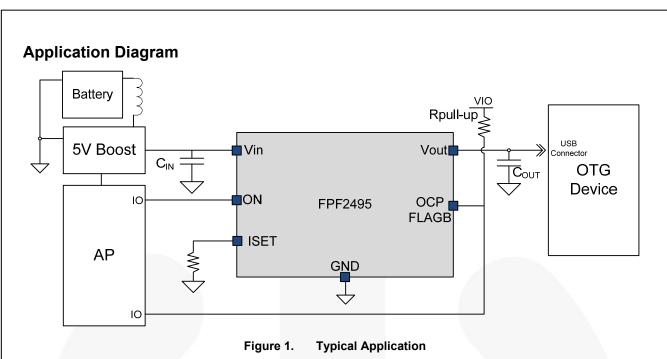
Description

The FPF2495 advanced load-management switch targets applications requiring a highly integrated solution. It disconnects loads powered from the DC power rail (<6 V) with stringent off-state current targets and high load capacitances (<100 μ F). The FPF2495 consists of a slew-rate controlled low-impedance MOSFET switch (100 m Ω maximum) and integrated analog features. The slew-rate controlled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on power rails. FPF2495 has over-voltage protection and over-temperature protection.

The FPF2495 has a True Reverse-Current Blocking (TRCB) function that obstructs unwanted reverse current from V_{OUT} to V_{IN} during ON and OFF states. The exceptionally low off-state current drain (<2 μ A maximum) facilitates compliance with standby power requirements. The input voltage range operates from 2.5 V to 5.5 V_{DC} to support a wide range of applications in consumer, optical, medical, storage, portable, and industrial-device power management. Switch control is managed by a logic input (active HIGH) capable of interfacing directly with low-voltage control signal / General-Purpose Input / Output (GPIO) without an external pull-down resistor.

The device is packaged in advanced, fully "green" compliant, 1.21 mm x 1.21 mm, Wafer-Level Chip-Scale Package (WLCSP).

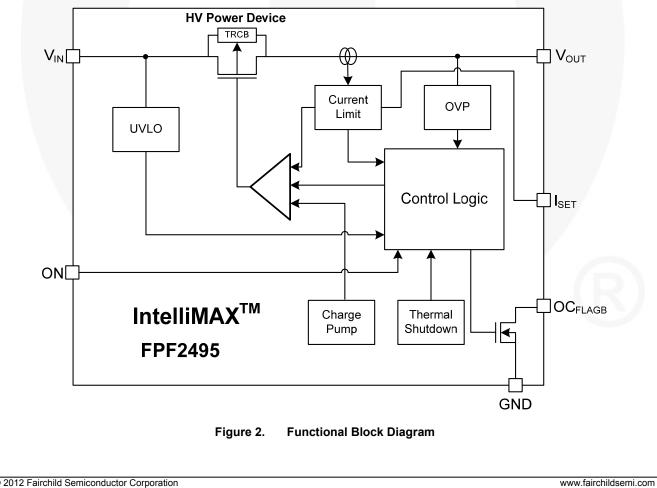
eraering in	ionnation .			
Part Number	Operating Temperature Range	Package	Packing Method	Top Mark
FPF2495UCX	-40 to 85°C	1.21 mm x 1.21 mm, Wafer-Level Chip-Scale Package (WLCSP)	Tape & Reel	ТН

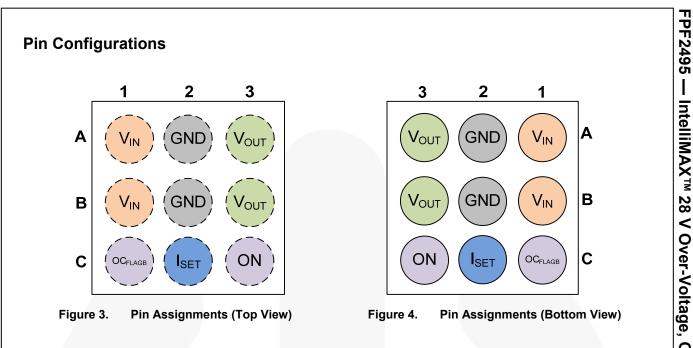


Note:

1. C_{IN} and C_{OUT} capacitors recommended for improvement of device stability.

Functional Block Diagram





Pin Description

Pin #	Name	Description		
A3, B3	V _{OUT}	Switch Output		
A1, B1	V _{IN}	Supply Input: Input to the power switch		
A2	GND	Ground (true device ground)		
B2	GND	Giodina (inde device giodina)		
C3	ON	ON/OFF Control Input: Active HIGH - GPIO compatible	Logic HIGH	Switch Enable
03	ON	Childringut. Active might - GP10 compatible	Logic LOW	Switch Disable
C1	OC _{FLAGB}	Fault Output: Active LOW, open-drain output that indicate pull-up resistor to V_{CC} is required.	es an input over o	current. External
C2	I _{SET}	Current Limit Set Input: A resistor from ISET to ground s	sets the current li	mit for the switch.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameters	Min.	Max.	Unit
V	V _{OUT} to GND, V _{OUT} to V _{IN}	u	-0.3	28.0	V
V _{PIN}	ON, VIN, FLAGB, ISET to C	GND	-0.3	6.0	v
I _{SW}	Maximum Continuous S	Maximum Continuous Switch Current ⁽⁴⁾			Α
t _{PD}	Total Power Dissipation at T _A =25°C			1.0	W
TJ	Operating Junction Tem	Operating Junction Temperature			°C
T _{STG}	Storage Junction Tempe	Storage Junction Temperature			°C
	Thermal Resistance, Ju	nction-to-Ambient		95 ⁽²⁾	°C/W
Θ_{JA}	(1-inch Square Pad of 2	oz. Copper)		110 ⁽³⁾	C/VV
	Electrostatic Discharge	Human Body Model, JESD22-A114	2.0		
ESD	Capability	Charged Device Model, JESD22-C101	2.5		137
ESD	IEC61000-4-2 System	Air Discharge (VIN, VON, VOUT to GND)	15.0		kV
	Level	Contact Discharge (V_{IN,} V_{ON,} V_{OUT} to GND)	8.0		

Notes:

- 2. Measured using 2S2P JEDEC std. PCB.
- 3. Measured using 2S2P JEDEC PCB cold plate method.
- 4. Maximum Junction Temperature = 85°C.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameters		Max.	Unit
VIN	Supply Voltage	2.5	5.5	V
T _A	Ambient Operating Temperature	-40	85	°C

Symbol	Parameters	Condition	Min.	Тур.	Max.	Unit
Basic Oper	ation					
V _{IN}	Input Voltage		2.5		5.5	V
I _{Q(OFF)}	Off Supply Current	V _{ON} =GND, V _{OUT} =Open		1	2	μA
I _{SD(OFF)}	Shutdown Current	V _{IN} =5.5 V, V _{OUT} =0 V, V _{ON} =GND		0.1	4.0	μA
IQ	Quiescent Current	I _{OUT} =0 mA		65	100	μA
_		V _{IN} =5.0 V, I _{OUT} =1 A		70	100	
Ron	On Resistance	V _{IN} =3.7 V, I _{OUT} =1 A		75	105	mΩ
R _{ON}	On Resistance ⁽⁶⁾	V _{IN} =5.0 V, I _{OUT} =1.5 A		70		mΩ
VIH	ON Input Logic HIGH Voltage	V _{IN} =2.5 V to 5.5 V	1.15			V
VIL	ON Input Logic LOW Voltage	V _{IN} =2.5 V to 5.5 V			0.65	V
N	FLAGB Output Logic	V _{IN} =5 V, I _{SINK} =10 mA		0.1	0.2	V
Vil_flag	LOW Voltage	V _{IN} =2.5 V, I _{SINK} =10 mA		0.15	0.30	V
I _{FLAGB_LK}	FLAGB Output HIGH Leakage Current	V _{IN} =5 V, Switch On			1	μA
I _{ON}	On Input Leakage	V _{ON} =0 V to V _{IN}			1.0	μA
R _{ON_PD}	Pull-Down Resistance at ON Pin	V _{IN} =2.5~5.5 V, V _{ON} =HIGH, T _A =-40 to 85°C		14		MΩ
Over-Voltaç	ge Protection				•	
	Output OV/D Lookout	V _{OUT} Rising Threshold	5.50	5.80	6.00	V
V _{OV_TRIP}	Output OVP Lockout	V _{OUT} Falling Threshold		5.50		
OUT _{HYS}	Output OVP Hysteresis	V _{OUT} Falling Threshold		0.3		V
tovp	OVP Response Time ⁽⁶⁾	$I_{OUT}{=}0.5$ A, C_L{=}1 $\mu\text{F},$ T_A{=}25°C, V_{OUT} from 5.5 V to 6.0 V	1		4 ⁽⁶⁾	μs
Over-Curre	nt Protection					
		$\begin{array}{l} V_{\text{IN}} \!$	42	50	58	
I _{LIM}	Current Limit	$V_{\text{IN}}\text{=}5$ V, $R_{\text{SET}}\text{=}2100~\Omega,$ $V_{\text{OUT}}\text{=}1.68$ to 5 V with 10% $\text{Accuracy}^{(5)}$	450	500	550	mA
		$V_{\text{IN}}\text{=}5$ V, $R_{\text{SET}}\text{=}1070~\Omega,$ $V_{\text{OUT}}\text{=}1.68$ to 5 V with 10% $\text{Accuracy}^{(5)}$	900	1000	1100	R
V _{UVLO}	Under-Voltage Lockout	V _{IN} Increasing		2.4		v
VUVLO	Under-Voltage Lockout	V _{IN} Decreasing		2.2		v
V _{UVLO_HYS}	UVLO Hysteresis			200		mV
V_{T_RCB}	RCB Protection Trip Point	V _{OUT} - V _{IN}		50		mV
V _{R_RCB}	RCB Protection Release Trip Point	V _{IN} - V _{OUT}		50		mV

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FPF2495 — IntelliMAX™ 28 V Over-Voltage, Over-Current Protection Load Switch with Adjustable Current-Limit Control

Electrical Characteristics (Continued)

Unless otherwise noted; V_{IN} =2.5 to 5.5 V, T_A =-40 to +85°C; typical values are at V_{IN} =5 V and T_A =25°C.

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Unit
$V_{\text{RCB}_{\text{HYS}}}$	RCB Hysteresis			100		mV
t _{RCB}	Default RCB Response Time	V _{IN} =5 V, V _{ON} =High/Low		2		μs
I _{RCB}	RCB Current	V _{ON} =0 V, V _{OUT} =5.5 V,		7		μA
t _{HOCP}	Hard Over-Current Response Time	Moderate Over-Current Condition, $I_{OUT} \ge I_{LIM}$, $V_{OUT}=0$ V		6		μs
t _{OCP}	Over-Current Response Time	Moderate Over-Current Condition, $I_{OUT} \ge I_{LIM} V_{OUT} \le V_{IN}$		7		μs
toc_flag	Over-Current Flag Response Time	When Over-Current Occurs to Flag Pulling LOW		8		ms
		Shutdown Threshold		150		
TSD	Thermal Shutdown	Return from Shutdown		130		°C
		Hysteresis		20		
ynamic C	haracteristics					
t _{DON}	Turn-On Delay ^(6,7)			0.67		ms
t _R	V _{OUT} Rise Time ^(6,7)			0.69		ms
t _{on}	Turn-On Time ^(6,8)	V _{IN} =5 V, R _L =100 Ω, C _L =1 μF,		1.36		ms
t _{DOFF}	Turn-Off Delay ^(7,6)	$T_A=25^{\circ}C, R_{SET}=2040 \Omega$		0.01		ms
t⊨	V _{OUT} Fall Time ^(7,6)			0.22		ms
t _{OFF}	Turn-Off Time ^(9,6)			0.23		ms
t _{DON}	Turn-On Delay ^(7,10)			0.65	0.78	ms
t _R	V _{OUT} Rise Time ^(7,10)			0.65	0.82	ms
ton	Turn-On Time ^(8,10)			1.3	1.6	ms
t _{DOFF}	Turn-Off Delay ^(7,10)	40 to 85°C, R _{SET} =634 Ω		4	10	μs
t _F	V _{OUT} Fall Time ^(7,10)			76	120	μs
t _{OFF}	Turn-Off Time ^(9,10)			80	130	μs

Notes:

5. Characterization based on 1% tolerance resistor.

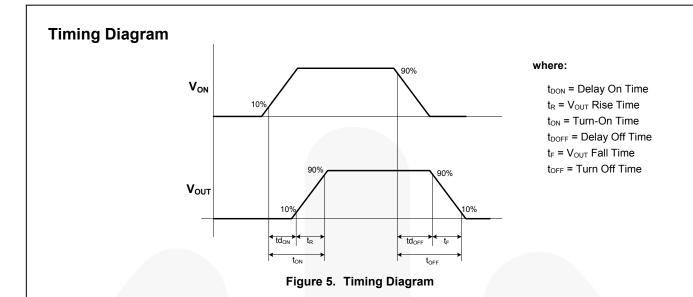
6. This parameter is guaranteed by design and characterization; not production tested.

7. $t_{DON}/t_{DOFF}/t_R/t_F$ are defined in Figure 5 below.

8. $t_{ON}=t_R + t_{DON}$.

9. $t_{OFF}=t_F + t_{DOFF}$.

10. This parameter is guaranteed by design.



Operation and Application Description

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into discharge load capacitor; a capacitor must be placed in between the V_{IN} and GND pins. A high-value capacitor on C_{IN} can be used to reduce the voltage drop in high-current applications.

Output Capacitor

An output capacitor should be placed between the V_{OUT} and GND pins. This capacitor prevents parasitic board inductance from forcing V_{OUT} below GND when the switch is on. This capacitor also prevents reverse inrush current from creating a voltage spike that could damage the device in the case of a V_{OUT} short.

Fault Reporting

Upon the detection of an over-current, OC_FLAGB signal the fault by activating LOW.

Current Limiting

The current limit ensures that the current through the switch does not exceed the maximum set value, while not limiting the minimum value. The current at which the part's limit is adjustable through the selection of the external resistor connected to the ISET pin. Information for selecting the resistor is found in the section below. The device acts as a constant-current source when the load draws more than the maximum value set by the device until thermal shutdown occurs. The device recovers if the die temperature drops below the threshold temperature.

Under-Voltage Lockout (UVLO)

The under-voltage lockout turns the switch off if the input voltage drops below the lockout threshold. With the ON pin active, the input voltage rising above the UVLO threshold releases the lockout and enables the switch.

True Reverse-Current Blocking

The true reverse-current blocking feature protects the input source against current flow from output to input regardless of whether the load switch is on or off.

Thermal Shutdown

The thermal shutdown protects the die from internally or externally generated excessive temperature. During an over-temperature condition, the switch is turned off. The switch automatically turns on again if the temperature of the die drops below the threshold temperature.

Setting Current Limit

The current limit is set with an external resistor connected between the I_{SET} and GND pins. The resistor is selected using Table 1. Resistor tolerance of 1% or less is recommended.

$R_{SET}\Omega$	Min. Current Limit (mA)	Typ. Current Limit (mA)	Max. Current Limit (mA)			
528	1800	2000	2200			
604	1570	1750	1920			
680	1350	1500	1650			
866	1125	1250	1375			
1070	900	1000	1100			
1200	810	900	990			
1330	720	800	880			
1500	630	700	770			
1740	540	600	660			
2100	450	500	550			
2320	405	450	495			
2550	360	400	440			
2940	315	350	385			
3400	370	300	330			
4020	225	250	275			
4990	180	200	220			
6490	135	150	165			
9530	90	100	110			
20000	42	50	58			

Table 1. Current Limit Settings by R_{SET}⁽¹¹⁾

Note:

11. Table values based on 1% tolerance resistor.

12. For 50 mA setting, tolerance is ±15% with 1%.

Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance may have on normal and short-circuit operation. Using wide traces for VIN, VOUT, GND helps minimize parasitic electrical effects along with minimizing the case-toambient thermal impedance.

Typical Performance Characteristics

T_A=25°C.

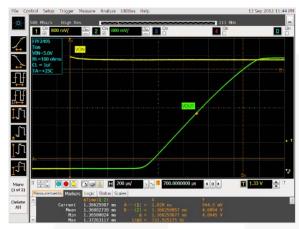


Figure 6. t_{on} Response



Figure 8. OC_FLAGB Response Time (Toggle R_{LOAD} from High to Low Resistance)



Figure 10. t_{OCP} Response Time



Figure 7. OVP Response (Increase V_{OUT} to OVP Trip Point)

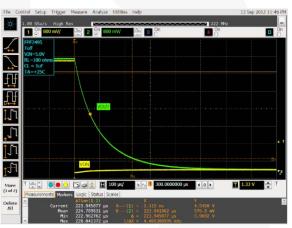
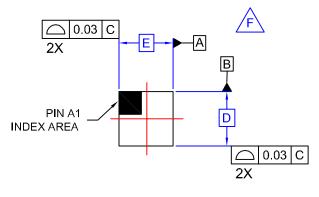


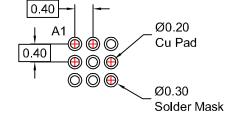
Figure 9. t_{OFF} Response

D	E	Х	Y
1210 µm ±30 µm	1210 μm ±30 μm	205 µm	205 µm

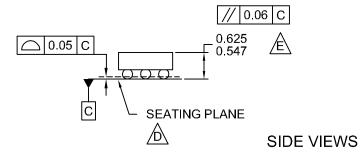
REVISIONS						
REV	DESCRIPTION	DATE	BY/SITE			
1	INITIAL DRAWING RELEASE.	2-15-2008	L. ENGLAND/FSME			
2	Updated land pattem to individual solder mask openings. Removed solder alloy note. Other misc updates for standardization.	4-9-2010	L. ENGLAND/FSME			

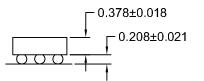


TOP VIEW



LAND PATTERN RECOMMENDATION (NSMD PAD TYPE)





NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASMEY14.5M, 1994.

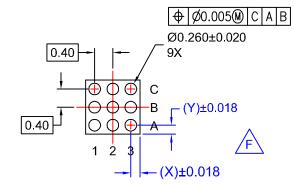
D DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.

E PACKAGE NOMINAL HEIGHT IS 586 MICRONS ±39 MICRONS (547-625 MICRONS).

F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

G. DRAWING FILNAME: MKT-UC009ABrev2

APPROVALS	DATE	FAIR		B		
L. England	4-9-10	SEMICO				
^{DFTG. CHK.} H. Allen						
ENGR. CHK.			-	50UM BALL		
		0	.411111	rnon, 2		
PROJECTIO	N	SCALE	SIZE	DRAWING NUMBER		REV
		N/A	N/A	MKT-l	JC009AB	2
		DO NO	T SCALE I	DRAWING	SHEET 1 of	1



BOTTOM VIEW

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